

Model of ELectron Output Non-linearity (MELON)





























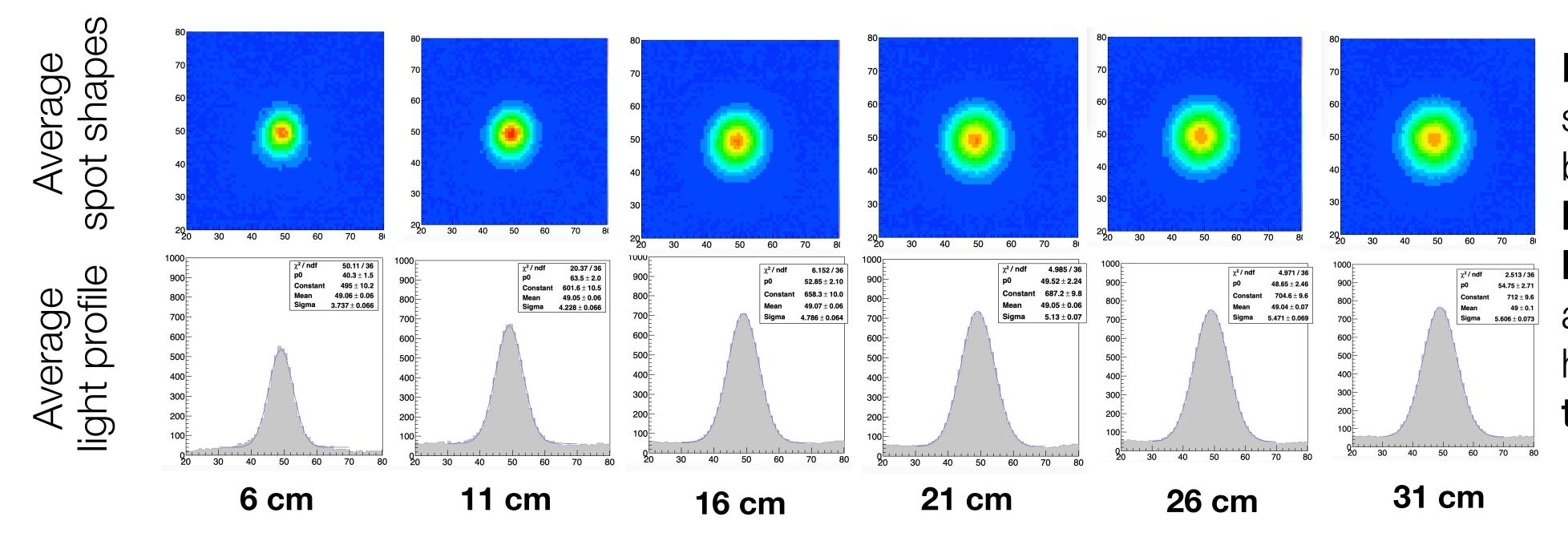
Experimental spot shapes



The interactions of ⁵⁵Fe 6 keV photons in the gas of an optical-readout TPC produces on the camera, roundish spots

In an ideal detector, the light in the spots (proportional to the released energy) is expected to be constant;

Since the area of the spots is expected to increase with the distance because of the primary electron diffusion, the brightness of the central core of the spots should decrease with the distance



Experimental data shows a different behaviour: the spots become larger with a brighter central part as long as interaction happens further from the GEM

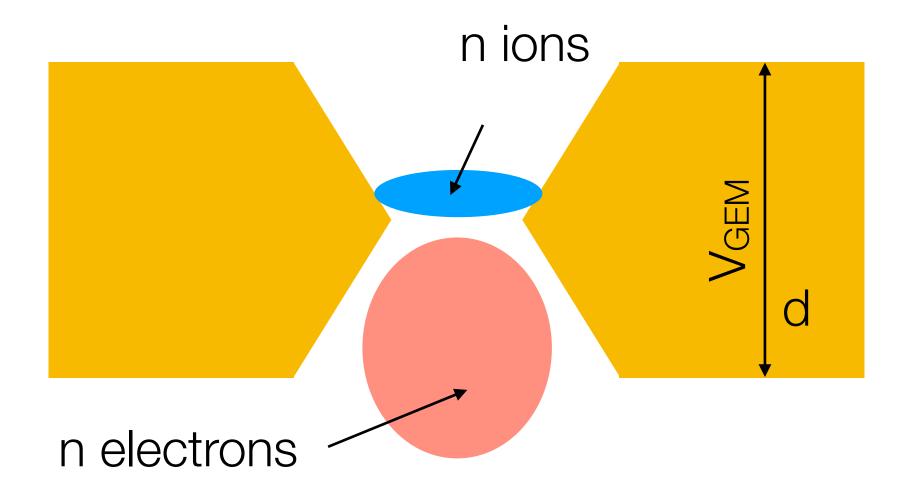


A simple model



Let's suppose that during the development of the avalanche within the GEM channels a significant amount of electrons are produced.

The **positive ions** slowly migrate toward the lower potential plane of the GEM, partially **shielding the GEM electric field** itself.



If **E**GEM = **V**GEM/**d** is the nominal electric field in the channel, we can suppose that after the production of n electron-ion pairs, the effective field becomes

$$E=E_{\mathrm{GEM}}(1-\beta n)$$
 where β is a screen scale factor

This effect increases for large number n_{in} of primaries entering the channel

Therefore, a **longer drift path** can **mitigate** this effect by **spreading the primaries** on a larger number of channels, then resulting in a **larger** effective **gain**



A simple model



In the usual **Townsend equation**

$$\frac{dn}{ds} = \alpha n$$

We can express the dependency of α on the electric field at the first order $\alpha=\tilde{\alpha}\cdot(E-E_{min})$

Where E_{min} is the minimum electric field to trigger the avalanche;

The **Townsend** equation becomes

$$\frac{dn}{ds} = \tilde{\alpha} \cdot (E_{\text{GEM}}(1 - \beta n) - E_{min}) n$$

By integrating it across the single channel, one obtains

$$G = \frac{n_{out}}{n_{in}} = \frac{c e^{\tilde{\alpha}V_{GEM}}}{1 + \beta' n_{in} (c e^{\tilde{\alpha}V_{GEM}} - 1)}$$

$$c = e^{-\tilde{\alpha}V_{min}} \quad V_{min} = E_{min}/d$$

$$\beta^{'} = \beta \; \frac{V_{GEM}}{V_{GEM} - V_{min}}$$

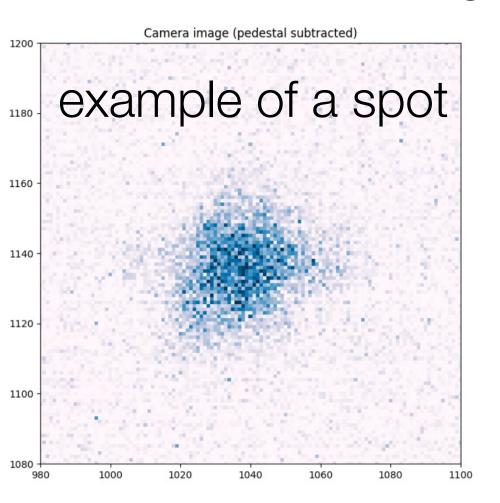


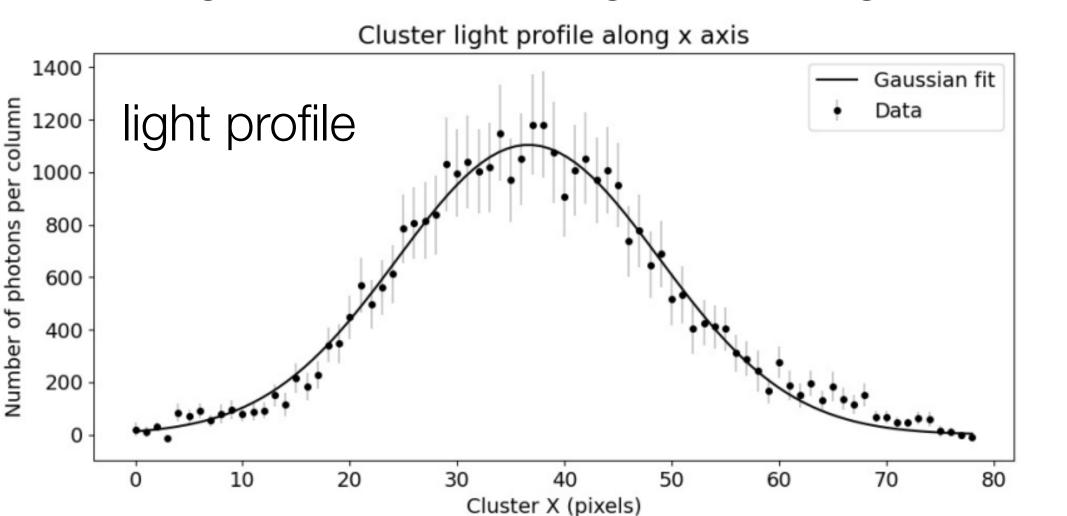
A simple model: the meaning of β



$$G = \frac{c e^{\tilde{\alpha}V_{GEM}}}{1 + \beta' n_{in} (c e^{\tilde{\alpha}V_{GEM}} - 1)}$$

- if $\beta' n_{in} \simeq 0 \to \text{negligible}$ screen effect $G = \tilde{G} = c \, e^{\tilde{\alpha} V_{GEM}}$ (typical exponential behaviour);
- if $\beta' n_{in} \simeq 1 \rightarrow \text{total}$ screen effect G = 1 (no gain at all);
- once the values of β , c and $\tilde{\alpha}$ are **fitted on data**, this simple modelization, allows to **simulate the** avalanche process in a GEM for any n_{in} (i.e. energy release and charge diffusion) value;
- To evaluate those parameters, the **above formula** was used to fit the behaviour of the gain for **three sets of experimental data** taken with all the three GEMs operating at the same voltage drops: **440V**, **430V** and **420V** as a function of the sigma of the gaussian describing the spot light profile

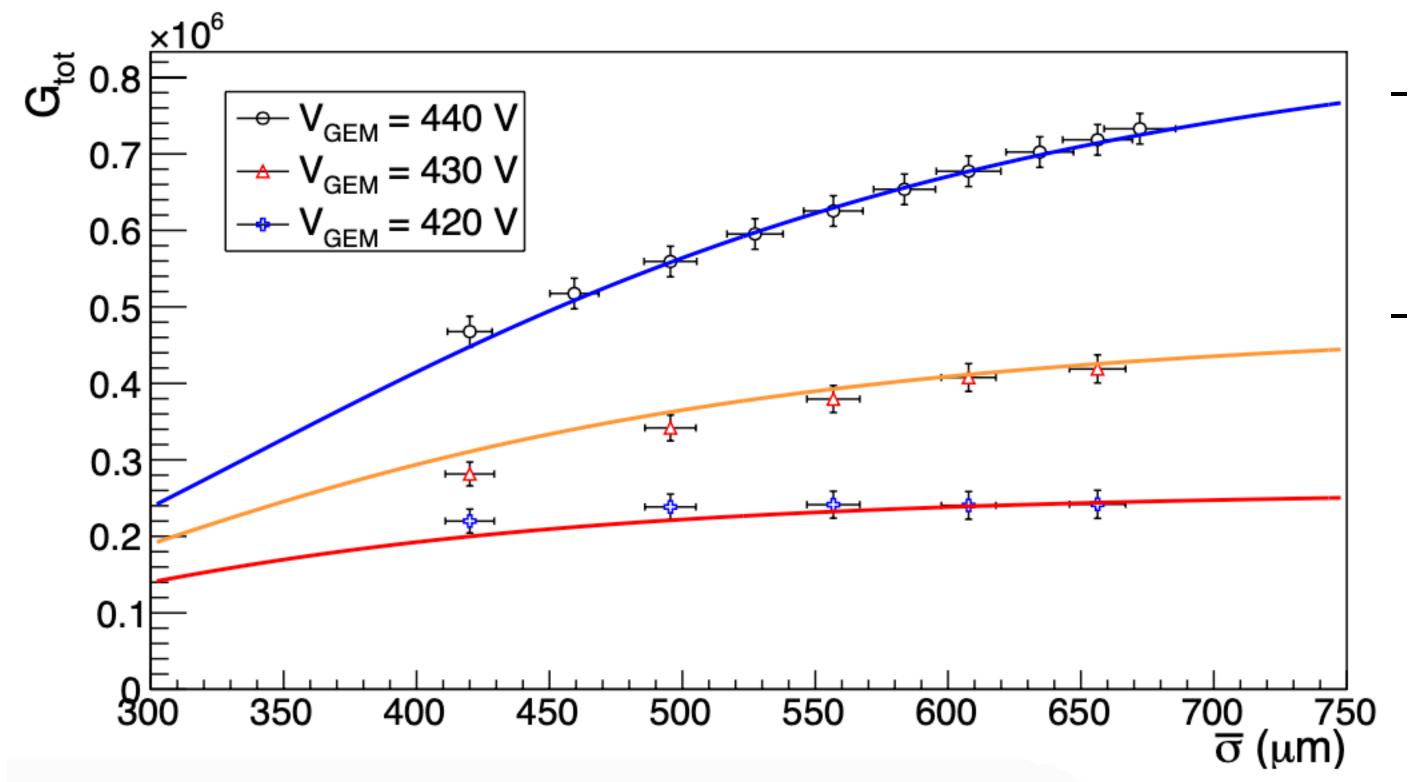






A simple model: an analytical fit





- The **analytical fit** is based on the simplistic assumptions of a **spherical electron cloud** with an **uniform electrons distribution**;
- It also allows to evaluate the values of the **non-saturated gains** at the different V_{GEM}

$$ilde{G}(V_{GEM} = 440V) = 135 \pm 12$$

 $ilde{G}(V_{GEM} = 430V) = 105 \pm 10$
 $ilde{G}(V_{GEM} = 420V) = 90 \pm 8$

- In the **real life** this is not the case and the **charge** are distributed according to **triple gaussian distribution** because of the **longitudinal** and **transverse** diffusion (that can be different);



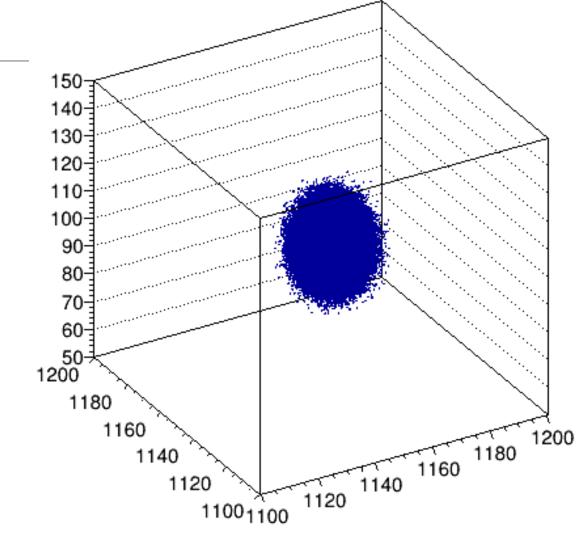
From the analytical to the numerical

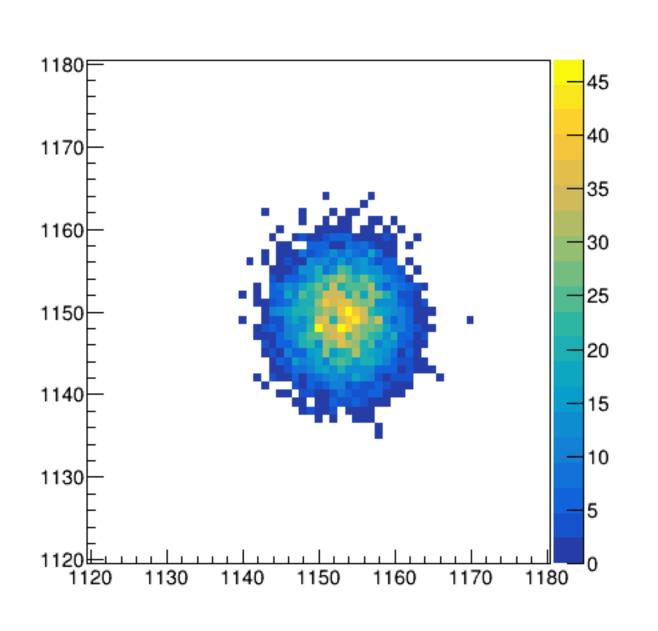


- We developed an custom-MC:
 - production, drift and diffusion of the primary electrons in gas (GEANT4);
 - at the GEM stack entrance, the cloud is split into (0.1 mm)³ voxels;
 - for each voxel, according to the number n_{in} of primaries, evaluate the number of exiting electrons n_{out} ;

$$n_{out} = n_{in} \frac{c e^{\tilde{\alpha}V_{GEM}}}{1 + \beta' n_{in} (c e^{\tilde{\alpha}V_{GEM}} - 1)}$$

- per each final electron, a random number of photons with average **0.07** is produced;
- photons are then **geometrically propagated** and the **optical system** response is evaluated: **vignetting**, **QE**, **sensitivity**
- Signal is then convolved with sensor thermal noise





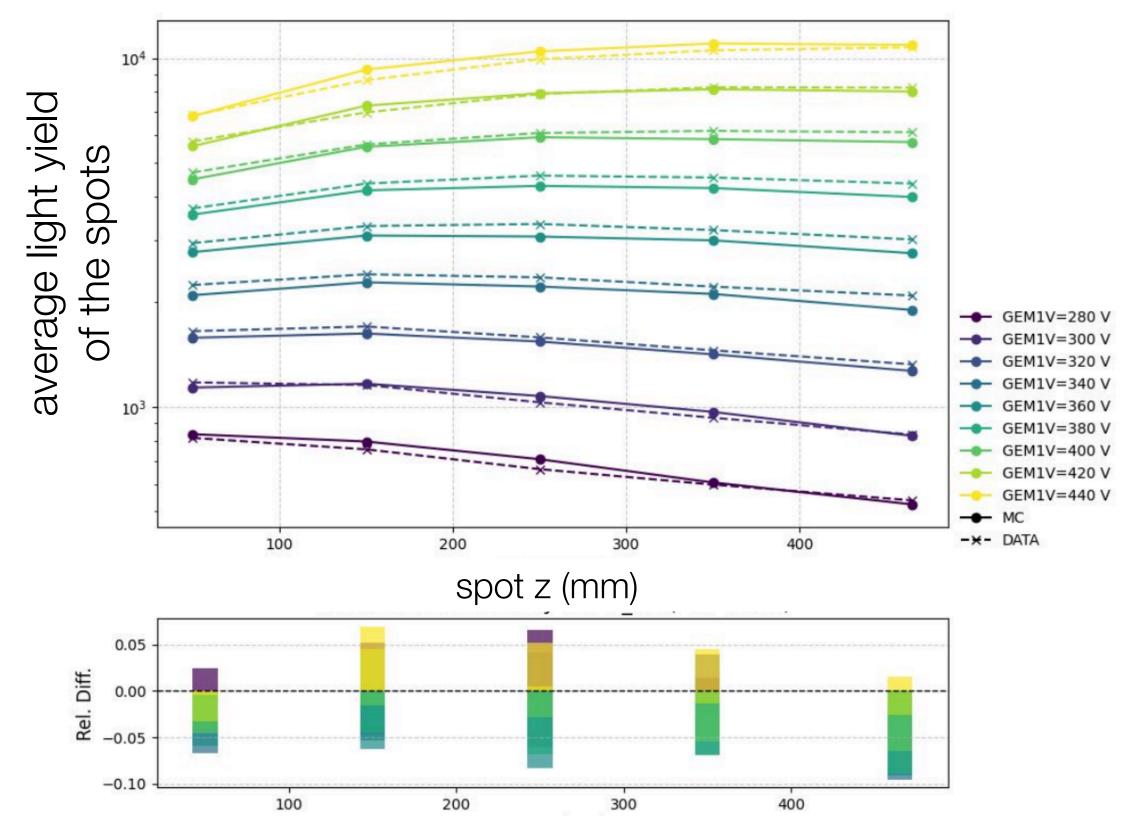


Comparison with experimental data



- To evaluate the **reliability** of this custom-MC, we took **three sets** of data by illuminating the TPC with the ⁵⁵Fe source, in different **z** positions;
- By **varying** the voltage drop on the first **V**_{GEM1}, **different** amounts of **charges** on the **GEM3** were obtained;

- Simulated and experimental data were then reconstructed and analysed with the same algorithms
- This plot shows the behaviour of the average spot light yield as a function of the drift path
- Over two orders of magnitude an agreement better than 10% was found



Cluster light profile along x axis

light profile

1000

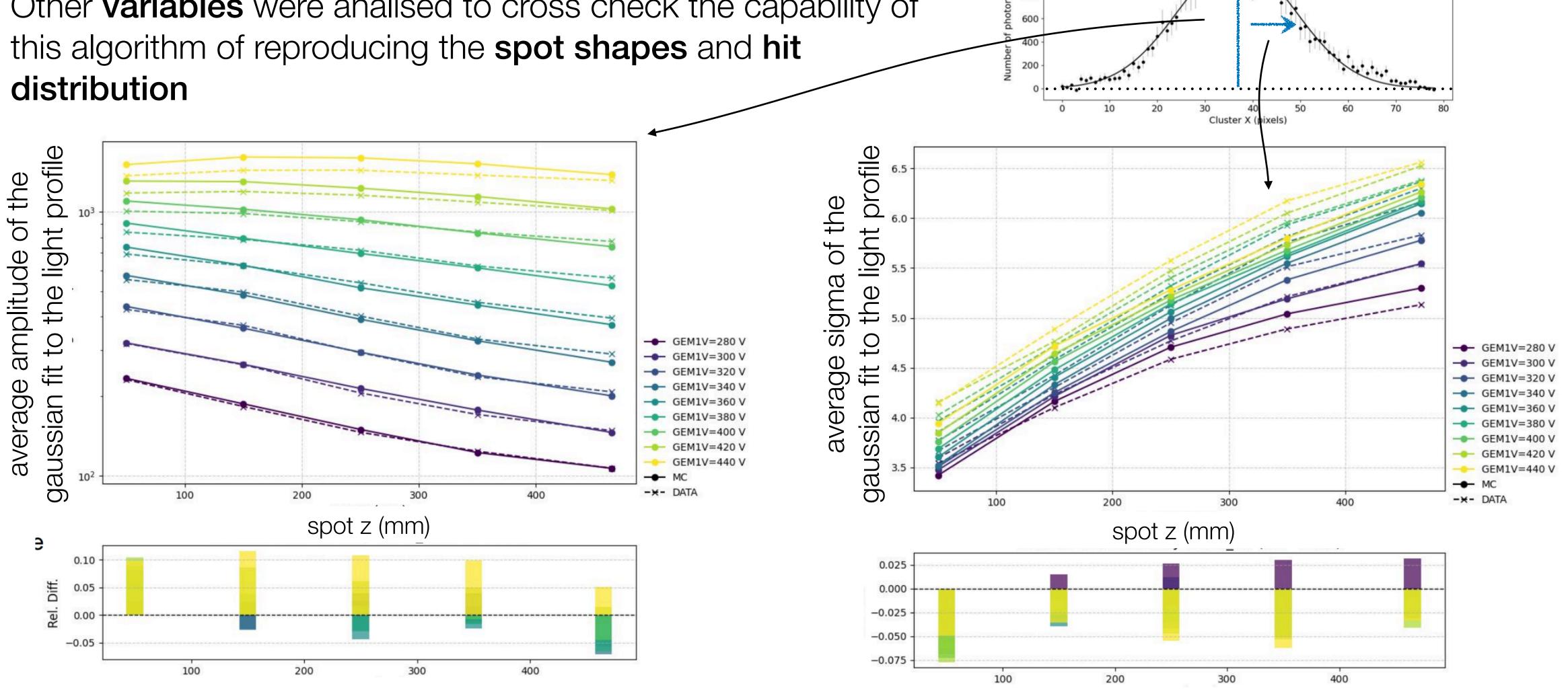
— Gaussian fit

Data



Comparison with experimental data

Other variables were analised to cross check the capability of

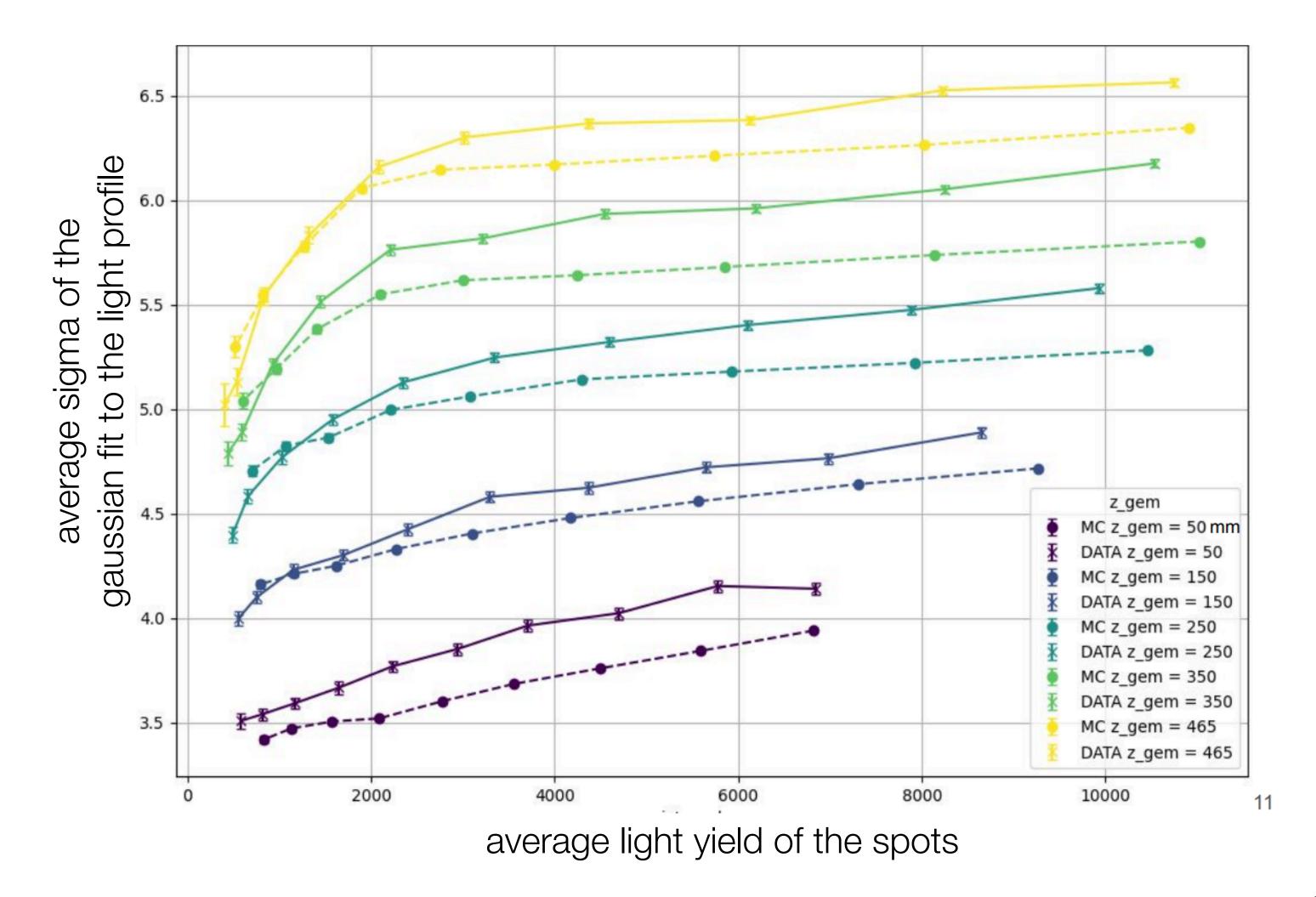




Comparison with experimental data



- This algorithm is also capable of reproducing an "instrumental effect": even if in principle the width of the light profile is only expected to be due to the diffusion, a sigma increasing with the gain was measured;
- The analysis of the simulated events showed that this was mainly due to some inefficiencies to properly reconstruct the borders of the spots, leading to a lower evaluated sigma;

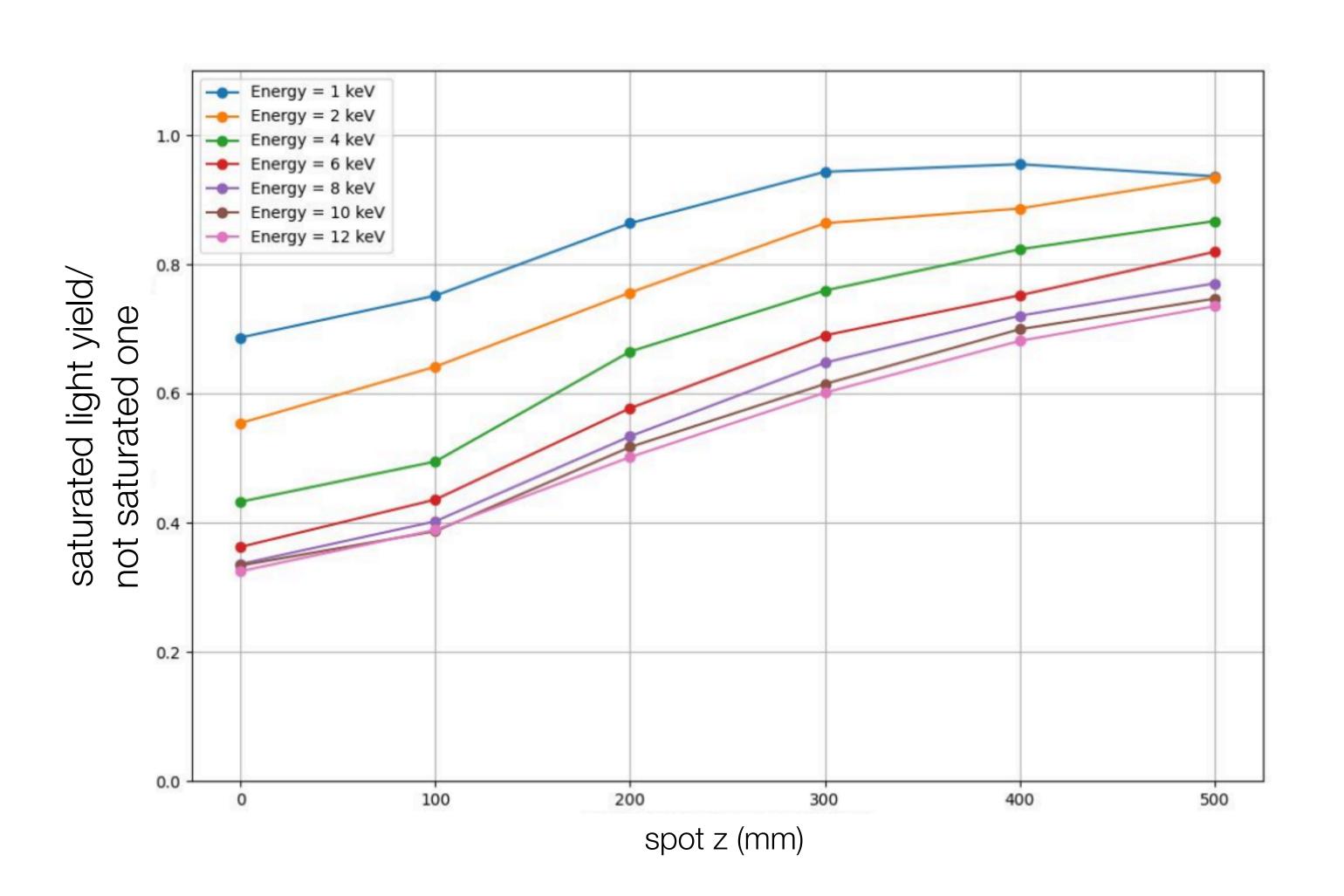




Evaluation of the saturation values



- Once the free parameter of the model are fitted, we can also evaluate the light yield suppression for spots produced by photons of different energies;
- It is interesting to see that already for **1 keV interactions**, the signal decreases to **70%** for event close to the GEM stack;



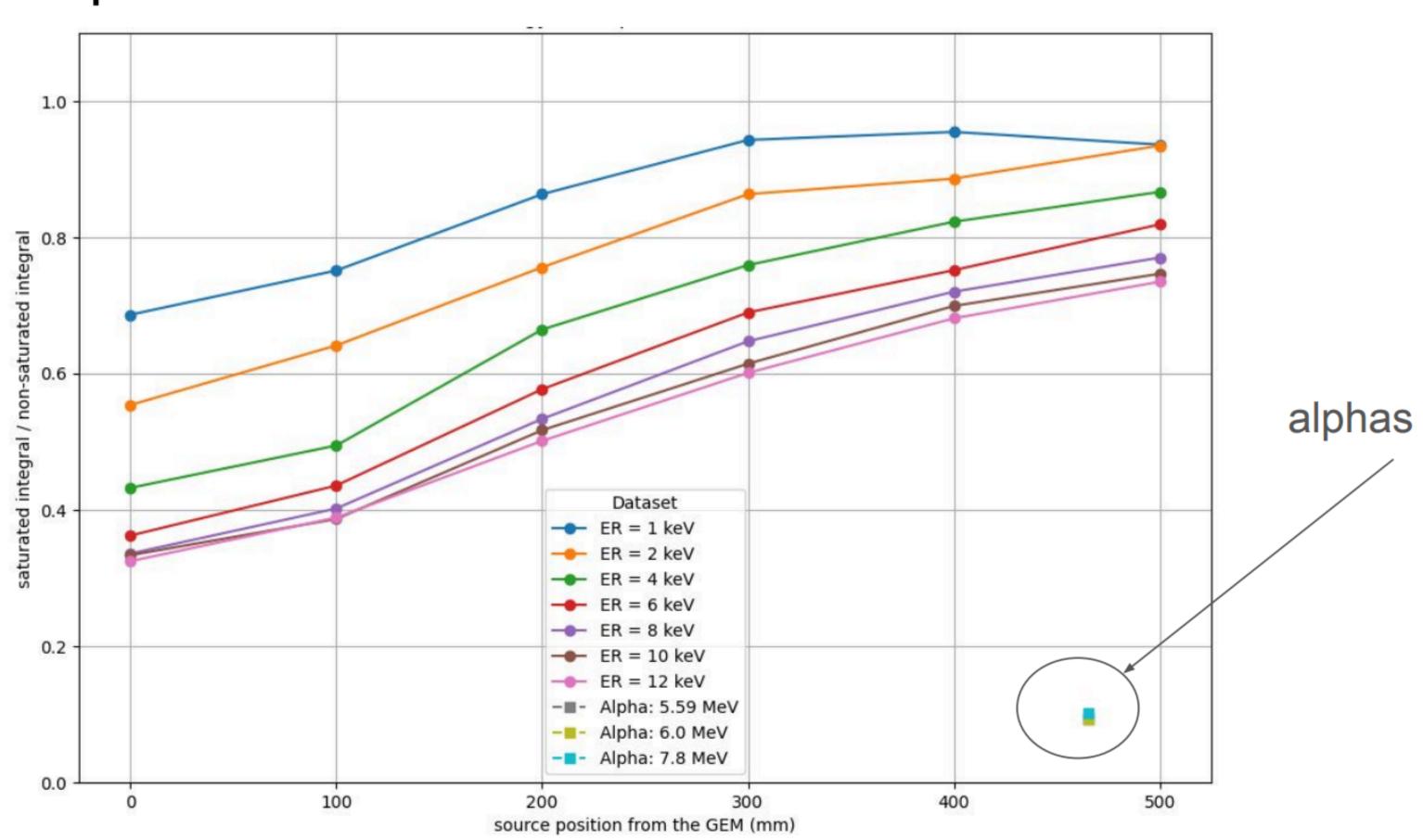


Evaluation of the saturation values



And alphas...

- Once the free parameter of the model are fitted, we can also evaluate the light yield suppression for spots produced by photons of different energies;
- It is interesting to see that already for **1 keV interactions**, the signal decreases to **70%** for event close to the GEM stack;
- 5-8 MeV alphas have a signal suppression of a factor of 10





Conclusion



The gain of the GEM depends on the number of secondaries created within the channels;

Therefore, it depends on:

- ionization density;
- diffusion;
- nominal gain of the channel;

A **simple model** based on a **modified Townsend equation** was developed and was then **used within a more general algorithm** (MELON) simulating **all steps** from the **energy deposit** to the formation of the optical **signal on the sensor**;

From a comparison with experimental data, this model resulted of **being able to reproduce** X rays spots with **5%-10% precision**;

It is then used by the CYGNO collaboration to evaluate the detector response;

It can also provide the basis **to correct** for this **non-linear response** if, for example, **z** can be **reconstructed**

